
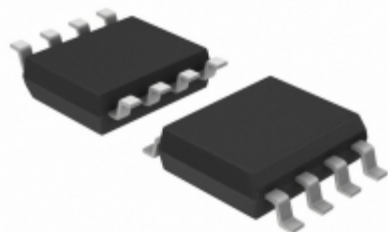


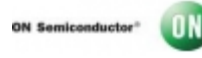


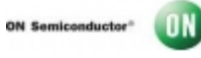


	<h2 style="color: orange;">NTMSD6N303R2SG</h2>
	<p>Hersteller-Teilenummer: NTMSD6N303R2SG</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 6A 8-SOIC</p> <p>Datenblätter:  NTMSD6N303R2SG.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 15000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTMSD6N303R2SG
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 6A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	15000 pcs Stock
Serie	FETKY™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOIC
Verlustleistung (max)	2W (Ta)
Typ FET	N-Channel
FET-Merkmal	Schottky Diode (Isolated)
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A (Ta)
Rds On (Max) @ Id, Vgs	32 mOhm @ 6A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	950pF @ 24V
Verpackung	Tape & Reel (TR)


















































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Sie können auch interessiert sein:

 <p>NTMSD6N303R2 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 6A 8-SOIC</p>	 <p>NTMSD3P303R2G AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V 2.34A 8-SOIC</p>	 <p>NTMSD3P303DR2G AMI Semiconductor / ON Semiconductor NTMSD3P303DR2G ON</p>	 <p>NTMSD3P102R2 AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.34A 8-SOIC</p>
 <p>NTMSD6N303R2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 6A 8-SOIC</p>	 <p>NTMSD2P10LR2G AMI Semiconductor / ON Semiconductor NTMSD2P10LR2G ON</p>	 <p>NTMSD6N03R2G ON NTMSD6N03R2G ON</p>	 <p>NTMSD3P102R2G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.34A 8-SOIC</p>

heiße Teile

Mehr

 NTMS4503NR2G	 NTMS4700NR	 NTMS4700NR2G	 NTMS4704NR2G	 NTMS4705NR2G
 NTMS4706NR2G	 NTMS4800NR2G	 NTMS4801N	 NTMS4801NR2G	 NTMS4802N
 NTMS4802NR2G	 NTMS4807N	 NTMS4807NR2G	 NTMS4816N	 NTMS4816NG
 NTMS4816NR2G	 NTMS4840NR2G	 NTMS4872NR2G	 NTMS4873NFR2G	 NTMS4916AS001
 NTMS4916N	 NTMS4916NR2G	 NTMS4916UT001	 NTMS4917NR2G	 NTMS4917UT001
 NTMS4920N	 NTMS4920NR2G	 NTMS4937N	 NTMS4937NR2G	 NTMS4939N
 NTMS4939NR2G	 NTMS4N01R2	 NTMS4P01R2G	 NTMS5835NL	 NTMS5835NLR2G
 NTMS5838NLR2G	 NTMS5P02	 NTMS5P02R2	 NTMS5P02R2G	 NTMS7N03R2
 NTMS7N03R2G	 NTMS7N03R2R2G	 NTMSD2P102LR2	 NTMSD2P102R2	 NTMSD3P102R2
 NTMSD3P102R2SG	 NTMSD3P303R2	 NTMSD6N03R2G	 NTMSD6N303R2	 NTMSD6N303R2G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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